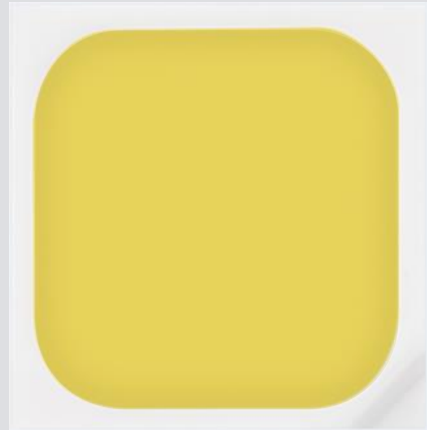


Middle Power LED Series 3030

LM301D

S95



Features & Benefits

- 0.3 W class middle power LED
- Mold resin for high reliability
- Standard form factor for design flexibility (3.0 × 3.0 mm)

Table of Contents

1.	Characteristics	-----	3
2.	Product Code Information	-----	4
3.	Typical Characteristics Graphs	-----	12
4.	Outline Drawing & Dimension	-----	15
5.	Reliability Test Items & Conditions	-----	16
6.	Soldering Conditions	-----	17
7.	Tape & Reel	-----	18
8.	Label Structure	-----	21
9.	Packing Structure	-----	22
10.	Precautions in Handling & Use	-----	26

1. Characteristics

a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Ambient / Operating Temperature	T_a	-40 ~ +85	°C	-
Storage Temperature	T_{stg}	-40 ~ +100	°C	-
LED Junction Temperature	T_j	125	°C	-
Forward Current	I_F	200	mA	-
Pulse Forward Current	I_{FP}	600	mA	Duty 1/10, pulse width 10ms
Assembly Process Temperature	-	260 <10	°C s	-
ESD (HBM)	-	5	kV	-

b) Electro-optical Characteristics ($I_F = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)

Item	Unit	Rank	Bin	Min.	Typ.	Max.
Forward Voltage (VF)	V	WA	AY	2.6	-	2.7
			AZ	2.7	-	2.8
Reverse Voltage (@ 5 mA)	V			0.7	-	1.2
Color Rendering Index (R_a)	-	8		95	-	-
Thermal Resistance (junction to solder point)	°C/W			-	12	-
Beam Angle	°			-	120	-

c) Color Rendering index ($I_f = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)

Nominal CCT (K)	Min								Unit
	CRI	R9	R10	R11	R12	R13	R14	R15	
2700	95	95	95	85	90	90	95	90	-
3000	95	90	90	85	90	95	95	90	
3500	95	90	90	85	90	90	95	90	
4000	95	85	90	85	90	95	95	90	
5000	95	85	90	85	90	95	95	90	
5700	95	85	90	85	90	95	95	90	
6500	95	80	90	85	90	95	95	90	

Note:

Samsung maintains measurement tolerance of: forward voltage = $\pm 0.1 \text{ V}$, luminous flux = $\pm 5 \%$, CRI = ± 3 , R9~R15 = ± 6.5

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	M	W	H	3	3	2	6	M	S	8	W	A	V	0	S	D

Digit	PKG Information	Code	Specification
1 2 3	Samsung Package Middle Power	SPM	Middle power
4 5	Color	WH	White
6	Product Version	3	Zener-in
7 8 9	Form Factor	326	3.0 x 3.0 x 0.65 mm; 2 pads
10	Sorting Current	M	65 mA
11	Chromaticity Coordinates	S	MacAdam
12	CRI	8	Min. 95
13 14	Forward Voltage (V)	WA	2.6 ~ 2.8 Bin Code AY 2.6 ~ 2.7 AZ 2.7 ~ 2.8
15 16	CCT (K)	W☆	2700 WN, WP, WQ, WR, WS, WT, WU
		V☆	3000 VN, VP, VQ, VR, VS, VT, VU
		U☆	3500 UN, UP, UQ, UR, US, UT, UU
		T☆	4000 Bin Code TN, TP, TQ, TR, TS, TT, TU
		R☆	5000 RN, RP, RQ, RR, RS, RT, RU
		Q☆	5700 QN, QP, QQ, QR, QS, QT, QU
		P☆	6500 PN, PP, PQ, PR, PS, PT, PU
☆ : "0" (Whole Bin) or "Y" (Y Kitting) or "3" (MacAdam 3 step)			
17 18	Luminous Flux (lm)	SD	Bin Code SD

a) Luminous Flux Bins($I_F = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)

Nominal CCT (K)	CRI Min.	Product Code	Flux Bin	Flux Range (Φ_v , lm)
2700	95	SPMWH3326MS8WAW☆SD	SD	21.0 ~ 25.0
3000	95	SPMWH3326MS8WAV☆SD	SD	21.5 ~ 25.5
3500	95	SPMWH3326MS8WAU☆SD	SD	23.0 ~ 27.0
4000	95	SPMWH3326MS8WAT☆SD	SD	23.0 ~ 27.0
5000	95	SPMWH3326MS8WAR☆SD	SD	24.0 ~ 28.0
5700	95	SPMWH3326MS8WAQ☆SD	SD	24.0 ~ 28.0
6500	95	SPMWH3326MS8WAP☆SD	SD	25.0 ~ 29.0

Note:

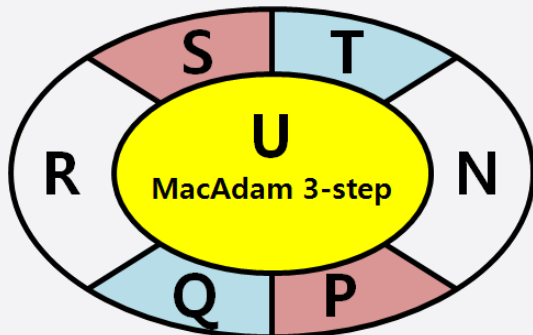
“☆” can be “0” (Whole bin), “3” (MacAdam 3-step), “Y” (Kitting).

b) Kitting Rule

1) Y Kitting Bin Concept

- Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin (Color).
- A Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

[Kitting example]



[Binning Information]

Item	Bin #1	Bin #2
VF	AY	AY
	AZ	AZ
CIE	U	U
	N	R
	P	S
	Q	T
IV	SD	SD

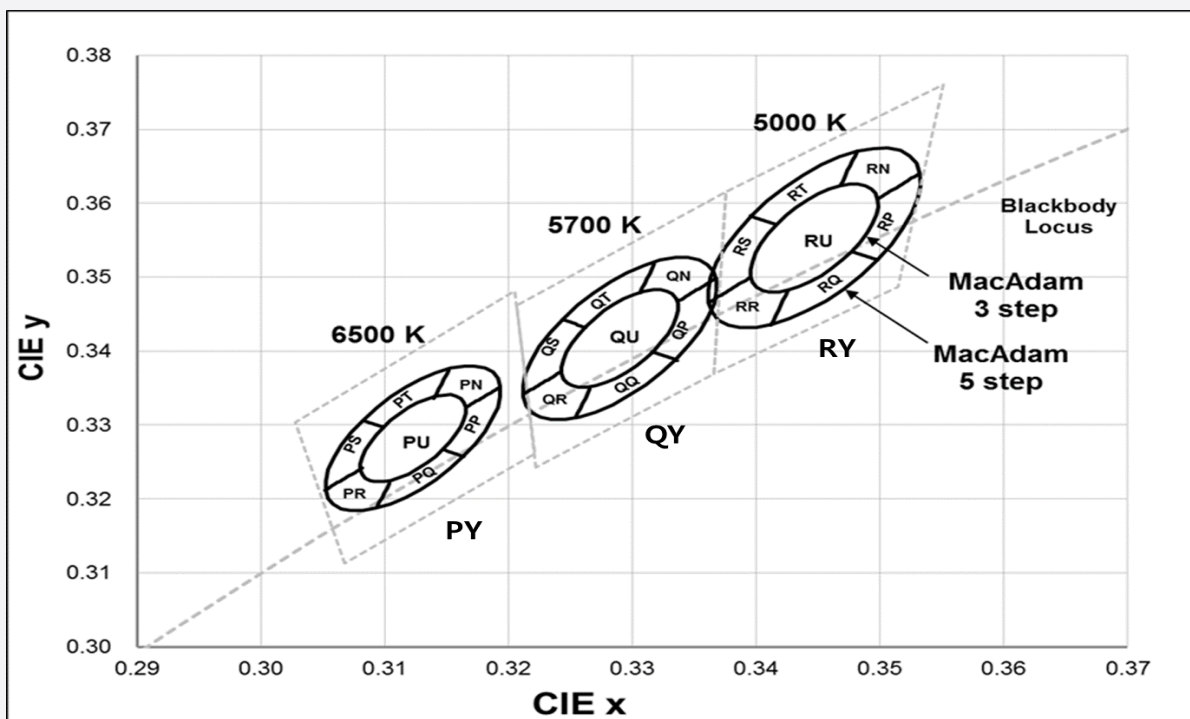
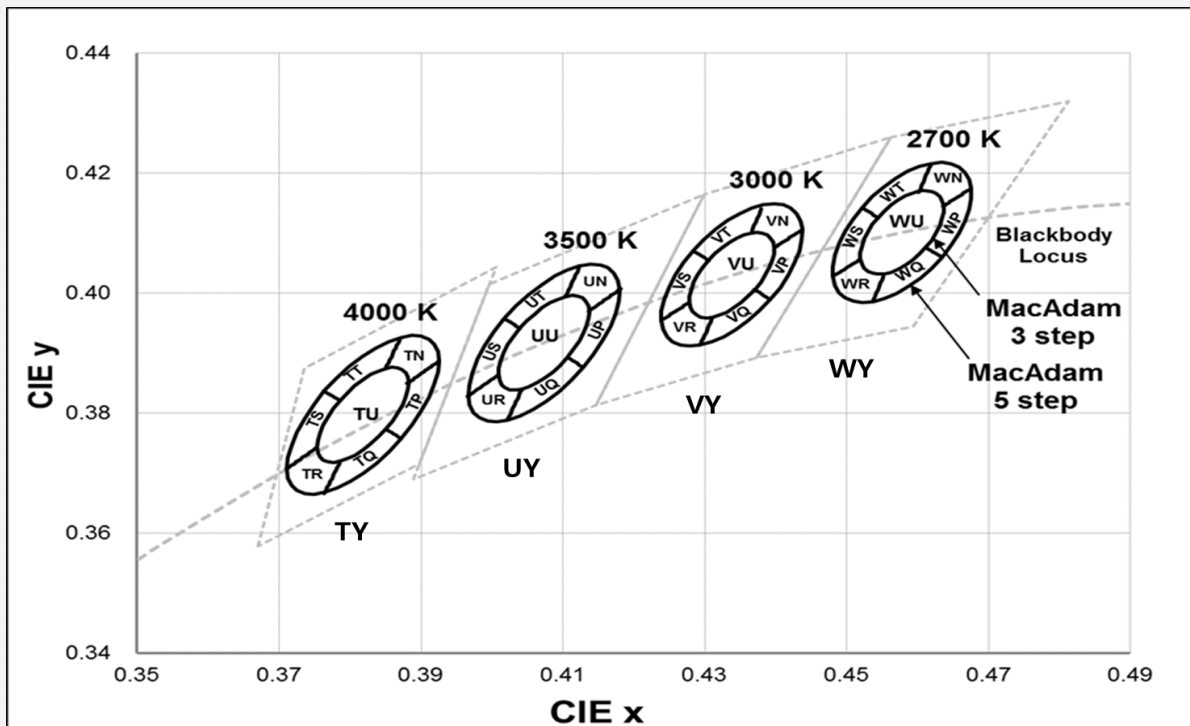
c) Color Bins ($I_f = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)

min. CRI (Ra)	Nominal CCT (K)	Product Code		Color Rank	Chromaticity Bins
80	2700	SPMWH3326MS8WAW0SD	W0	Whole bin	WN, WP, WQ, WR, WS, WT, WU
		SPMWH3326MS8WAW3SD	W3	MacAdam 3-step ellipse bin	WU
		SPMWH3326MS8WAWYSD	WY	Y Kitting	WN, WP, WQ, WR, WS, WT, WU
	3000	SPMWH3326MS8WAV0SD	V0	Whole bin	VN, VP, VQ, VR, VS, VT, VU
		SPMWH3326MS8WAV3SD	V3	MacAdam 3-step ellipse bin	VU
		SPMWH3326MS8WAVYSD	VY	Y Kitting	VN, VP, VQ, VR, VS, VT, VU
	3500	SPMWH3326MS8WAU0SD	U0	Whole bin)	UN, UP, UQ, UR, US, UT, UU
		SPMWH3326MS8WAU3SD	U3	MacAdam 3-step ellipse bin	UU
		SPMWH3326MS8WAUYSD	UY	Y Kitting	UN, UP, UQ, UR, US, UT, UU
	4000	SPMWH3326MS8WA T0SD	T0	Whole bin	TN, TP, TQ, TR, TS, TT, TU
		SPMWH3326MS8WAT3SD	T3	MacAdam 3-step ellipse bin	TU
		SPMWH3326MS8WATYSD	TY	Y Kitting	TN, TP, TQ, TR, TS, TT, TU
	5000	SPMWH3326MS8WAR0SD	R0	Whole bin	RN, RP, RQ, RR, RS, RT, RU
		SPMWH3326MS8WAR3SD	R3	MacAdam 3-step ellipse bin	RU
		SPMWH3326MS8WARYSD	RY	Y Kitting	RN, RP, RQ, RR, RS, RT, RU
	5700	SPMWH3326MS8WAQ0SD	Q0	Whole bin	QN, QP, QQ, QR, QS, QT, QU
		SPMWH3326MS8WAQ3SD	Q3	MacAdam 3-step ellipse bin	QU
		SPMWH3326MS8WAQYSD	QY	Y Kitting	QN, QP, QQ, QR, QS, QT, QU
	6500	SPMWH3326MS8WAP0SD	P0	Whole bin	PN, PP, PQ, PR, PS, PT, PU
		SPMWH3326MS8WAP3SD	P3	MacAdam 3-step ellipse bin	PU
		SPMWH3326MS8WAPYSD	PY	Y Kitting	PN, PP, PQ, PR, PS, PT, PU

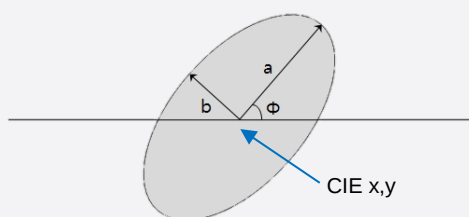
d) Voltage Bins ($I_F = 65\text{ mA}$, $T_s = 25^\circ\text{C}$)

CRI (R_a) Min.	Nominal CCT (K)	Product Code	Voltage Rank	Voltage Bin	Voltage Range (V)
-	-	-	WA	AY	2.6 ~ 2.7
				AZ	2.7 ~ 2.8

e) Chromaticity Region & Coordinates ($I_F = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)



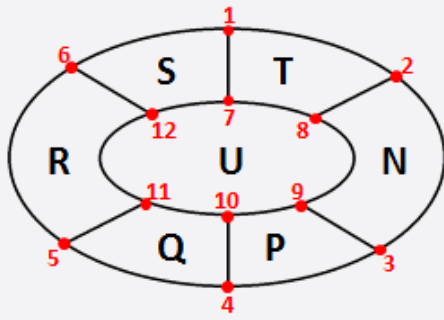
f) Chromaticity Region & Coordinates ($I_F = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)



MacAdam	CCT (K)	Center point		Major-axis	Minor-axis	Rotation
		CIE x	CIE y	a	b	Φ
3 step	2700	0.4578	0.4101	0.0081	0.0042	53.70
	3000	0.4338	0.4030	0.0083	0.0041	53.22
	3500	0.4073	0.3917	0.0093	0.0041	54.00
	4000	0.3818	0.3797	0.0094	0.0040	53.72
	5000	0.3447	0.3553	0.0082	0.0035	59.62
	5700	0.3287	0.3417	0.0075	0.0032	59.10
	6500	0.3123	0.3282	0.0067	0.0029	58.57
5 step	2700	0.4578	0.4101	0.0135	0.0070	53.70
	3000	0.4338	0.4030	0.0138	0.0068	53.22
	3500	0.4073	0.3917	0.0155	0.0068	54.00
	4000	0.3818	0.3797	0.0157	0.0067	53.72
	5000	0.3447	0.3553	0.0137	0.0058	59.62
	5700	0.3287	0.3417	0.0125	0.0053	59.10
	6500	0.3123	0.3282	0.0112	0.0048	58.57

Note: Samsung maintains measurement tolerance of: $C_x, C_y = \pm 0.005$

g) Chromaticity Region & Coordinates



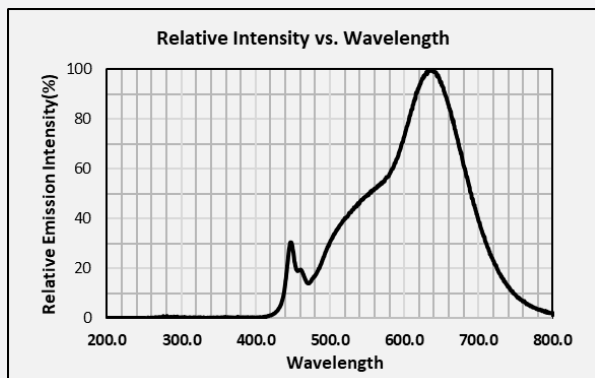
Region	2700K		3000K		3500K		4000K	
	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
1	0.4521	0.4142	0.4283	0.4071	0.4018	0.3957	0.3764	0.3837
2	0.4619	0.4216	0.4382	0.4146	0.4125	0.4046	0.3871	0.3926
3	0.4675	0.4175	0.4437	0.4105	0.4180	0.4005	0.3925	0.3887
4	0.4634	0.4059	0.4393	0.3989	0.4128	0.3877	0.3872	0.3758
5	0.4537	0.3986	0.4293	0.3913	0.4022	0.3788	0.3765	0.3668
6	0.4481	0.4028	0.4239	0.3954	0.3966	0.3828	0.3711	0.3707
7	0.4544	0.4126	0.4305	0.4054	0.4040	0.3941	0.3786	0.3821
8	0.4603	0.4170	0.4364	0.4100	0.4104	0.3994	0.3850	0.3874
9	0.4636	0.4145	0.4397	0.4075	0.4137	0.3970	0.3882	0.3851
10	0.4612	0.4076	0.4371	0.4005	0.4106	0.3893	0.3850	0.3773
11	0.4553	0.4032	0.4311	0.3960	0.4042	0.3840	0.3786	0.3720
12	0.4520	0.4057	0.4279	0.3984	0.4009	0.3864	0.3754	0.3743

Region	5000K		5700K		6500K	
	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y
1	0.3397	0.3583	0.3242	0.3445	0.3082	0.3307
2	0.3482	0.3670	0.3320	0.3524	0.3153	0.3377
3	0.3532	0.3640	0.3365	0.3496	0.3194	0.3352
4	0.3497	0.3524	0.3333	0.3390	0.3164	0.3257
5	0.3412	0.3436	0.3254	0.3310	0.3093	0.3187
6	0.3362	0.3465	0.3209	0.3338	0.3052	0.3212
7	0.3417	0.3571	0.3260	0.3434	0.3098	0.3297
8	0.3468	0.3623	0.3307	0.3481	0.3141	0.3339
9	0.3498	0.3605	0.3334	0.3464	0.3166	0.3324
10	0.3477	0.3535	0.3314	0.3401	0.3148	0.3267
11	0.3426	0.3483	0.3267	0.3353	0.3105	0.3225
12	0.3396	0.3500	0.3240	0.3369	0.3080	0.3240

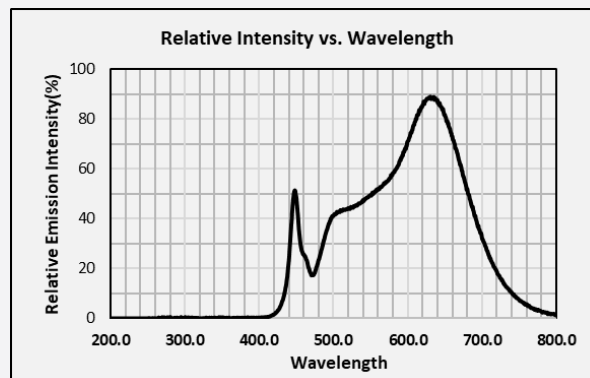
3. Typical Characteristics Graphs

a) Spectrum Distribution ($I_f = 65 \text{ mA}$, $T_s = 25^\circ \text{C}$)

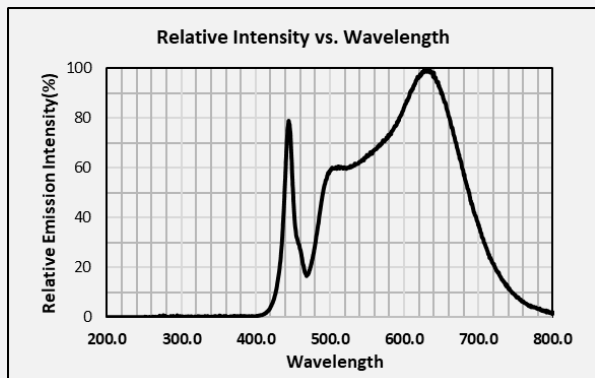
CCT : 2700K (95 CRI)



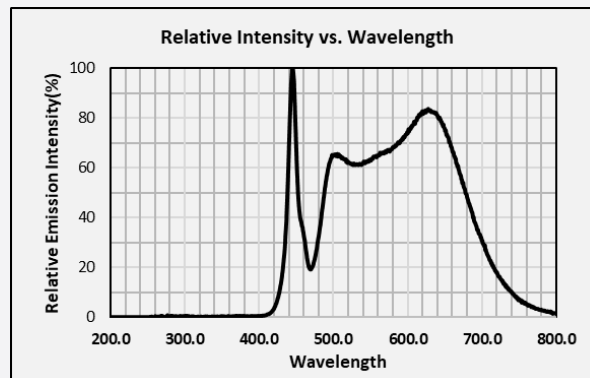
CCT : 3000K (95 CRI)



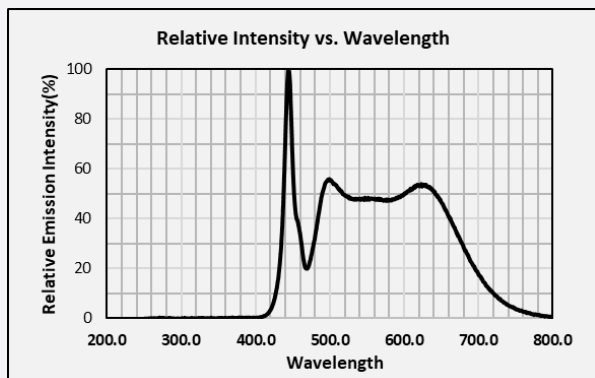
CCT : 3500K (95 CRI)



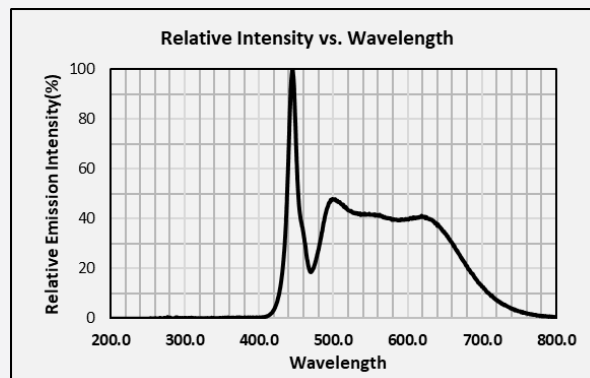
CCT : 4000K (95 CRI)



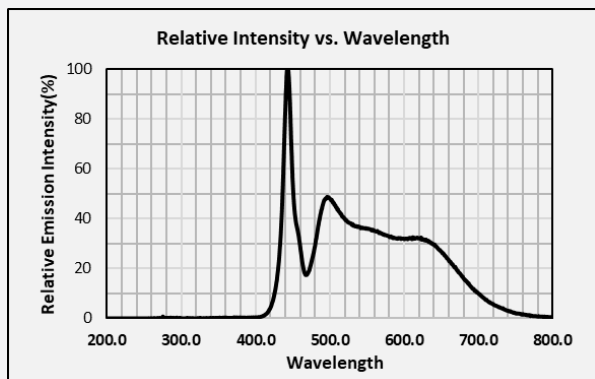
CCT : 5000K (95 CRI)



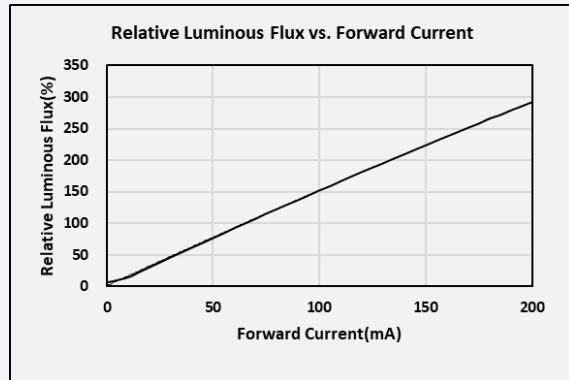
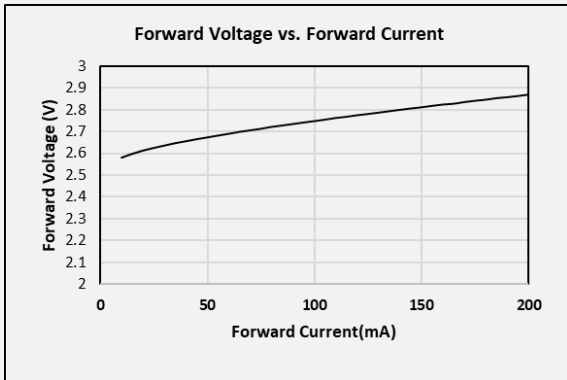
CCT : 5700K (95 CRI)



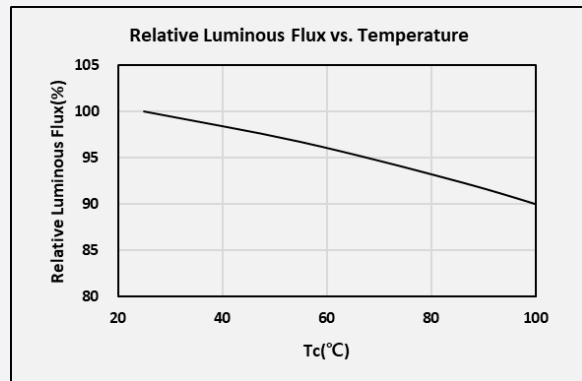
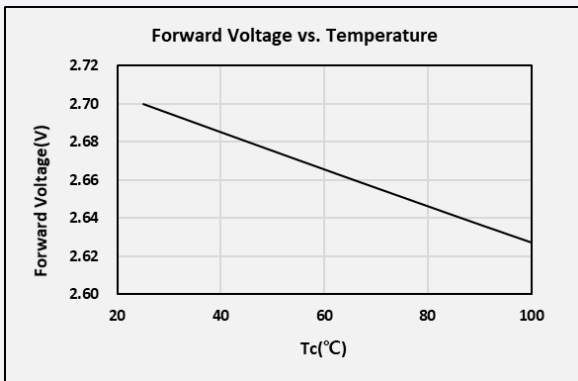
CCT : 6500K (95 CRI)



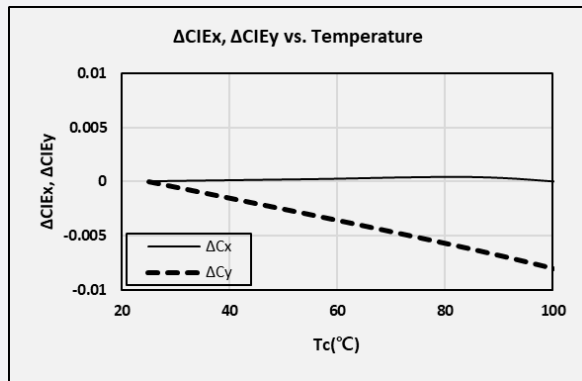
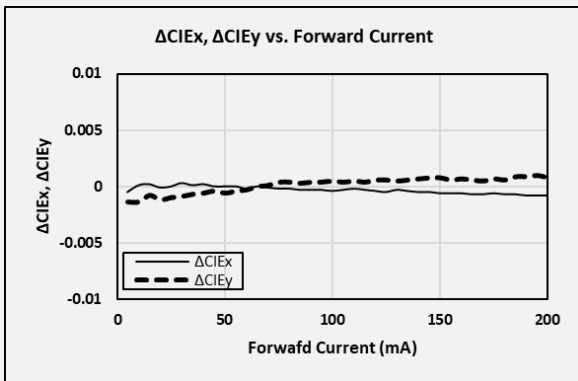
b) Forward Current Characteristics ($I_F = 65 \text{ mA}$, $T_s = 25^\circ\text{C}$)



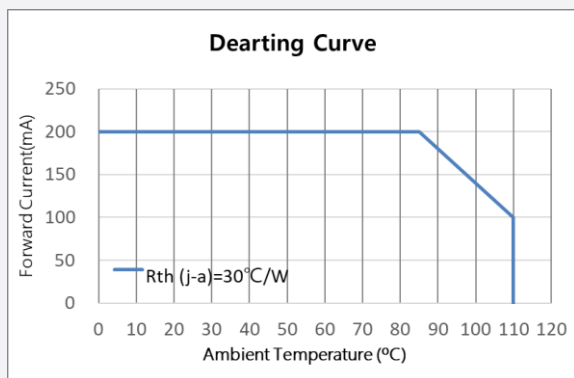
c) Temperature Characteristics ($I_F = 65 \text{ mA}$)



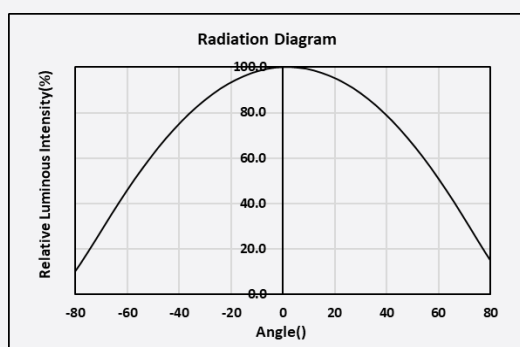
d) Color Shift Characteristics ($T_s = 25^\circ\text{C}$, $I_F = 65 \text{ mA}$)



e) Derating Curve



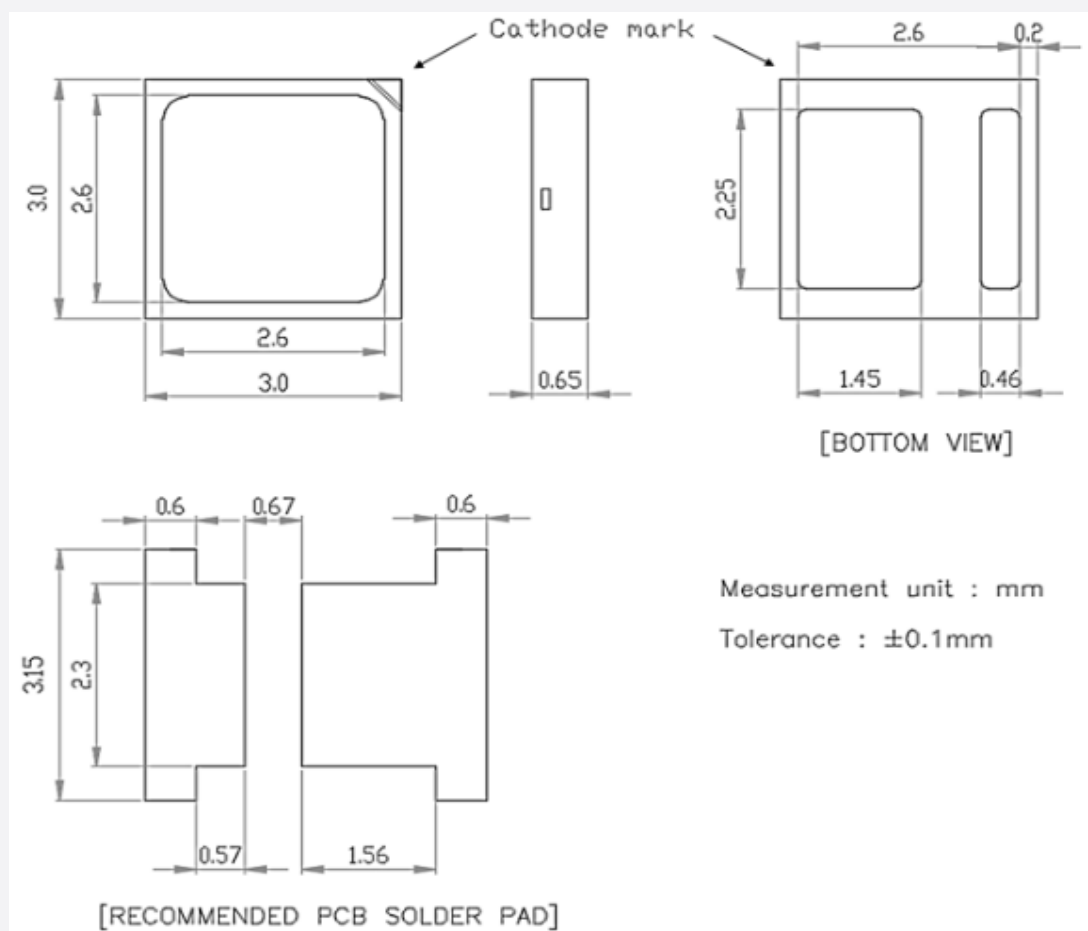
f) Beam Angle Characteristics (IF=65mA, Ts=25 °C)



Note: All characteristics shown are for reference only.

Derating characteristics will meet the criteria as detailed in the Reliability section within this specification.

4. Outline Drawing & Dimension



Notes:

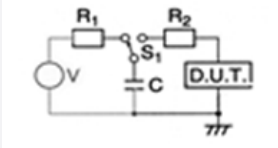
- 1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
- 2) T_s point and measurement method:
 - ① Measure one point at the cathode pad, if necessary remove PSR of PCB to reach T_s point.
 - ② All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

Precautions:

- 1) Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- 2) Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- 3) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

5. Reliability Test Items & Conditions

a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample No.
High Temperature Life Test	85 °C, DC Max current	1000 h	22
High Temperature Humidity Life Test	60 °C, 90 % RH, DC Max current	1000 h	22
Low Temperature Life Test	-40 °C, DC Max current	1000 h	22
Thermal Cycle	-45 °C / 15 min ↔ 125 °C / 15 min → Hot plate 180 °C	500 cycles	100
High Temperature Storage	120 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)	 R₁: 10 MΩ R₂: 1.5 kΩ C: 100 pF V: ±5 kV	5 times	30

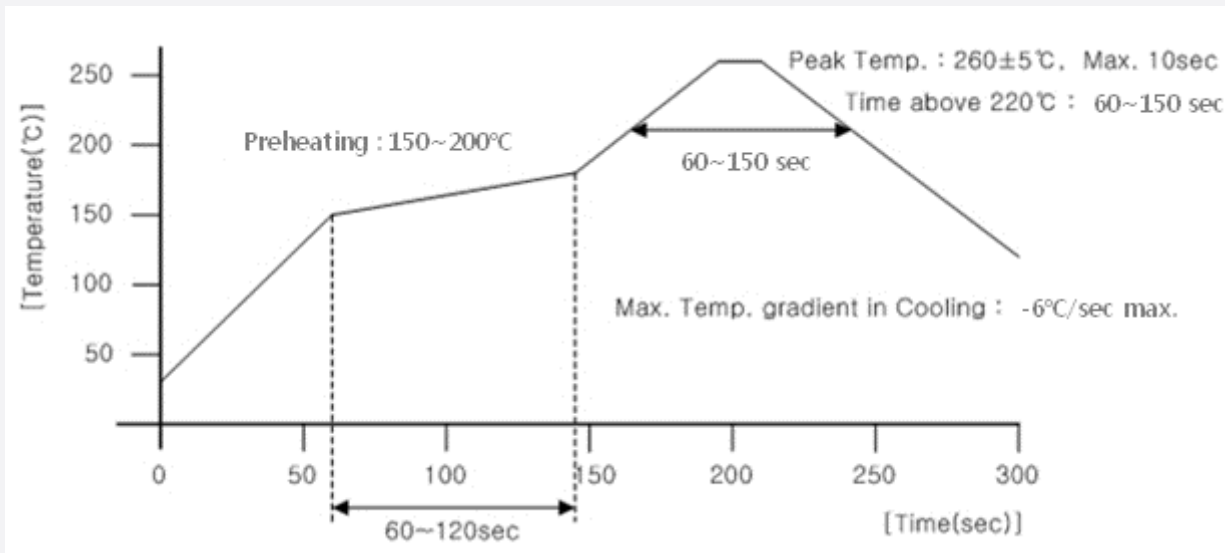
b) Criteria for Judging the Damage

Item	Symbol	Test Condition (T _s = 25 °C)	Limit	
			Min	Max
Forward Voltage	V _F	I _F = 65 mA	Init. Value * 0.9	Init. Value * 1.1
Luminous Flux	Φ _v	I _F = 65 mA	Init. Value * 0.7	Init. Value * 1.1

6. Soldering Conditions

a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.



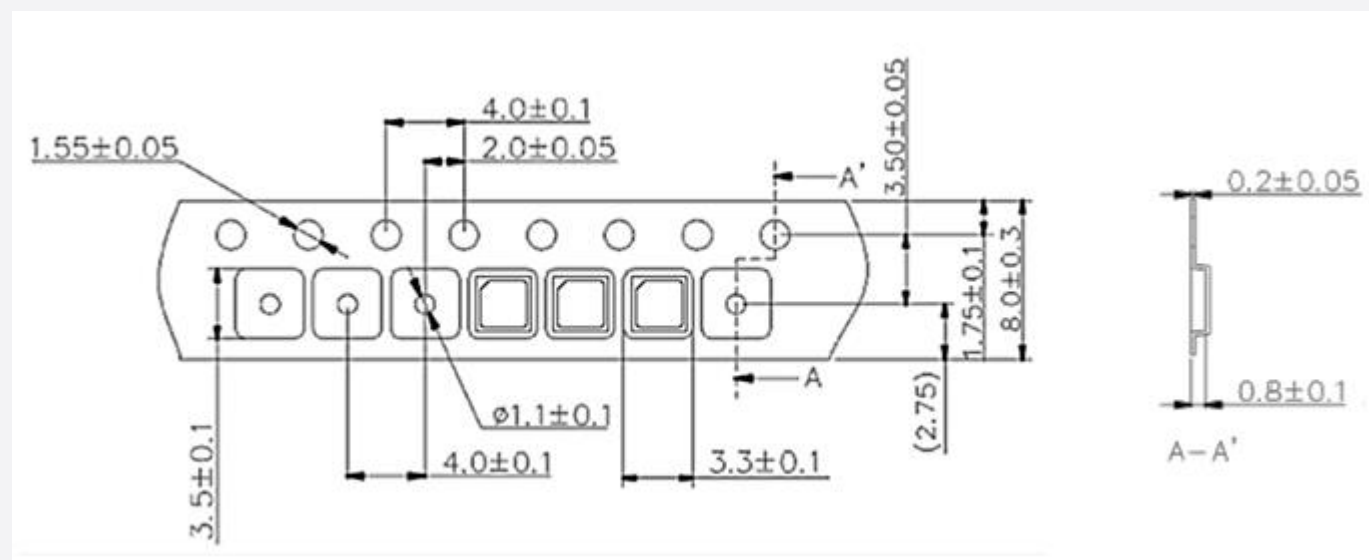
b) Manual Soldering Conditions

Not more than 5 seconds @ max. 300 °C, under soldering iron.

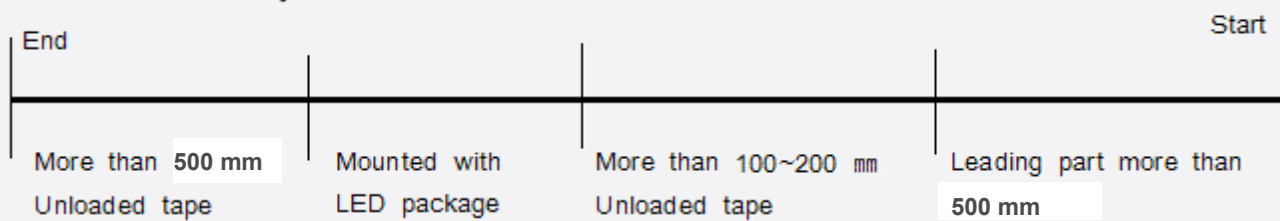
7. Tape & Reel

a) Taping Dimension

(unit: mm)

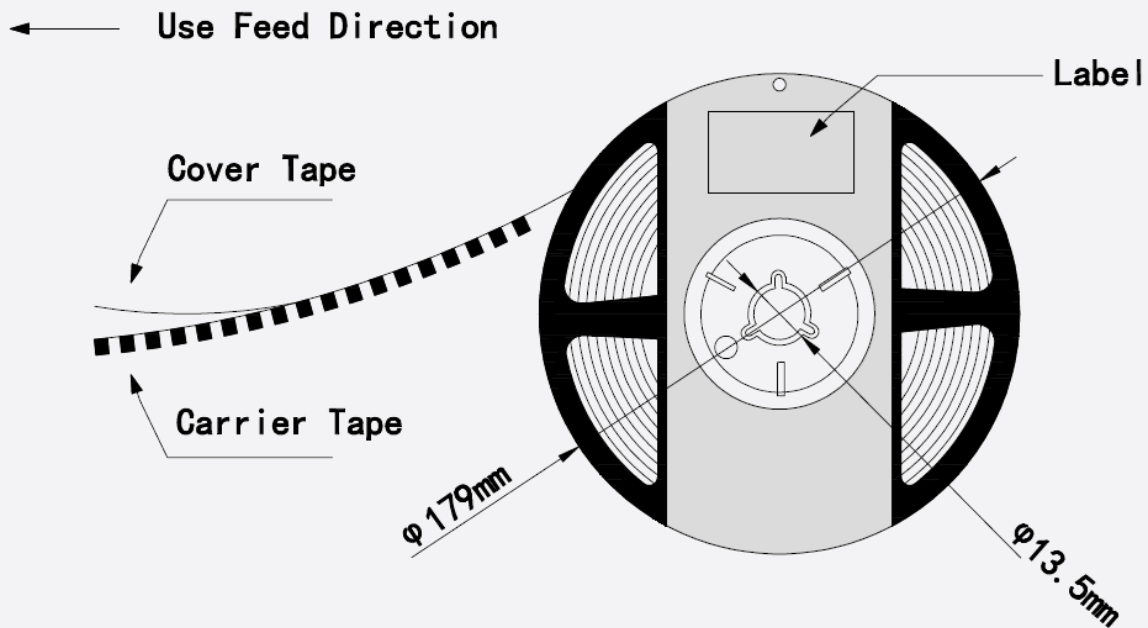


Taping Direction



b) Reel Dimension (max 4,000 pcs)

(unit: mm)

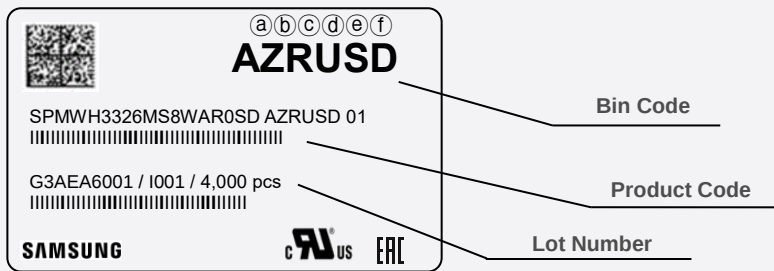


Notes:

- 1) Quantity : The quantity/reel is 4,000 pcs
- 2) Cumulative Tolerance : Cumulative tolerance / 10 pitches is ± 0.2 mm
- 3) Adhesion Strength of Cover Tape : Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
- 4) Packaging : P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

8. Label Structure

a) Label Structure



Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

a) b): Forward Voltage bin (refer to page 7)

c) d): Chromaticity bin (refer to page 8-10)

e) f): Luminous Flux bin (refer to page 5)

b) Lot Number

The lot number is composed of the following characters:



1 2 3 3 2 3 4 5 6 7 8 9 / I a b c / 4,000 pcs

1 2 : Production site (G3 : Nanchang, China)

3 : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)

4 : Year (F:2021, G2022 ...)

5 : Month (1~9, A, B, C)

6 : Day (1~9, A, B~V)

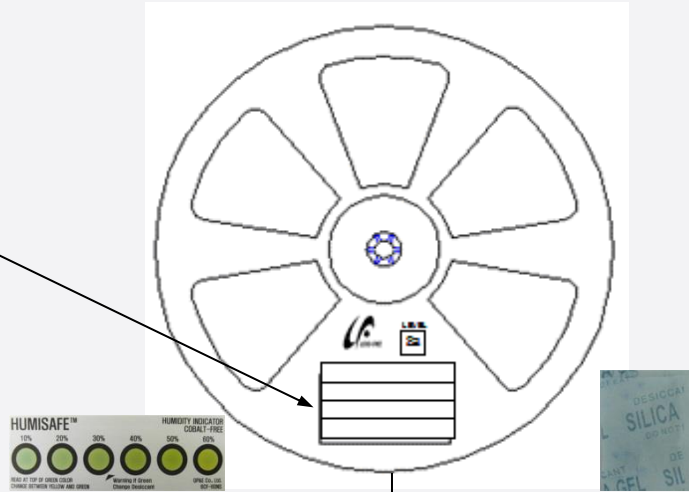
7 8 9 : Serial number (001 ~ 999)

a b c : Product serial number (001 ~ 999)

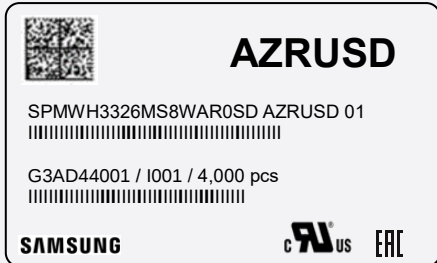
9. Packing Structure

a) Packing Process (The quantity of PKG on the Reel to be Max 4,000pcs)

Reel



Aluminum Vinyl Packing Bag

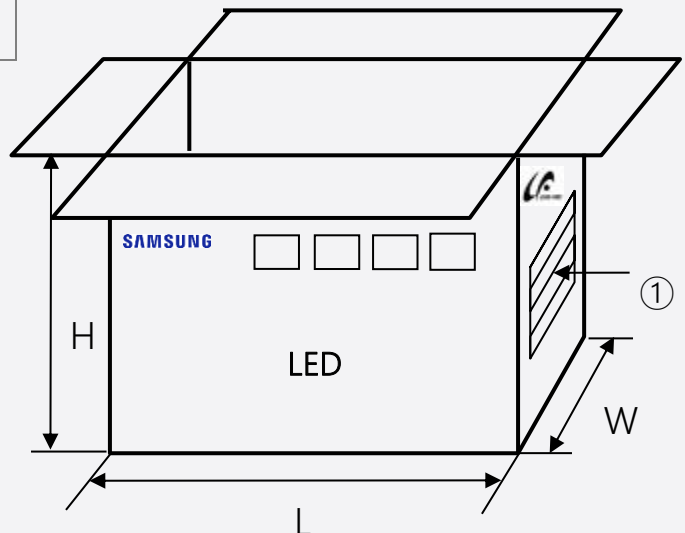


Outer Box

Material: Paper (SW3B(B))

Type	Size (mm)			Note
	L	W	H	
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels
7 inch S	245 ± 5	220 ± 5	86 ± 5	Up to 5 reels

① Side Label



b) Packing Process for kitting (The quantity of PKG on the Reel to be Max 4,000pcs)

Kitting 'A'



Kitting 'B'



Aluminum Vinyl Packing Bag

Kitting 'A'



Kitting 'B'



Outer Box

Kitting 'A'



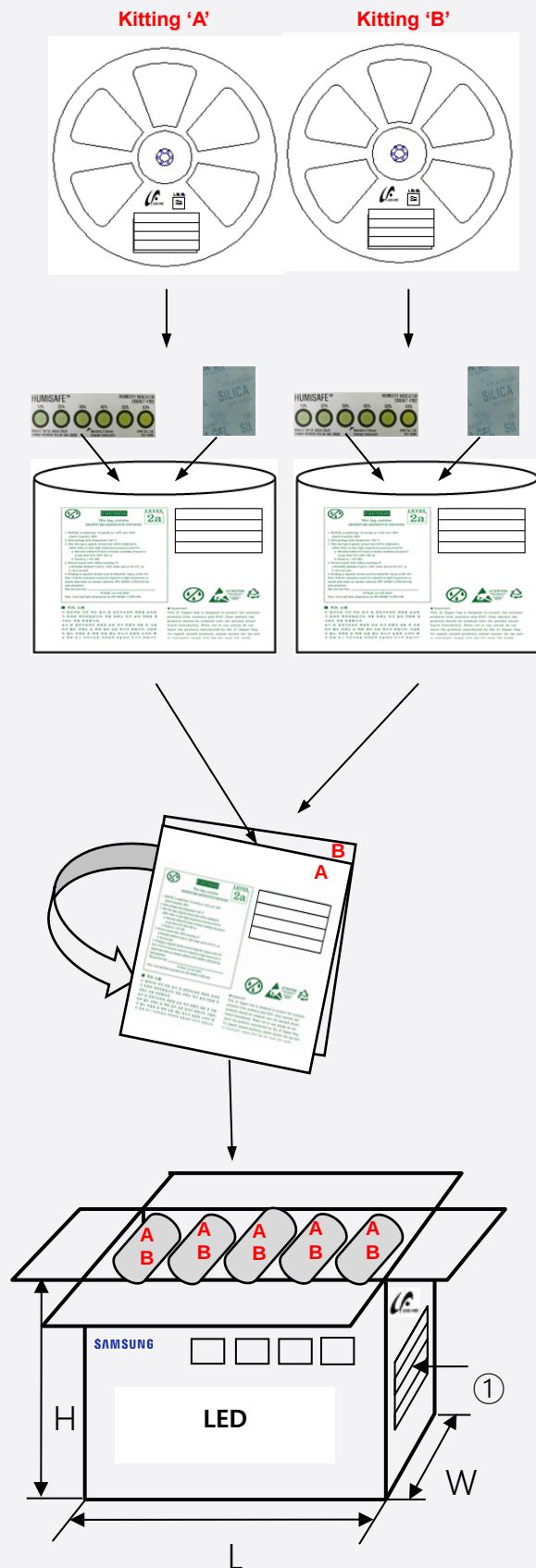
Kitting 'B'



Note: "★" can be Nominal CCT code.

Material: Paper (SW3B(B))

Type	Size (mm)			Note
	L	W	H	
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels



10. Precautions in Handling & Use

- 1) For over-current protection, users are recommended to apply resistors connected in series with the LEDs to mitigate sudden change of the forward current caused by shift of forward voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When cleaning is required, IPA is recommended as the cleaning agent. Some solvent-based cleaning agent may damage the silicone resins used in the device.
- 3) When the device is in operation, the forward current should be carefully determined considering the maximum ambient temperature and corresponding junction temperature.
- 4) LEDs must be stored in a clean environment. Shelf life of sealed bags is 12 months at temperature 0~40 °C, 0~90 % RH.
- 5) After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
 - a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH*^{Note 1}, or
 - b. Mounted within 24 hours (1 day) at an assembly line with a condition of more than 30 °C / 70 % RH*^{Note 2}, or
 - c. Stored at <10 % RH.

*Note 1, 2: IPC/JEDEC J-STD-033A, Recommended Equivalent Total Floor Life Table

Package Type and Body Thickness	Moisture Sensitivity Level	Maximum Percent Relative Humidity						Temperature
		40%	50%	60%	70%	80%	90%	
Body Thickness <2.1mm	Level 2a	∞	∞	28	1	1	1	30°C
		∞	∞	∞	2	1	1	25°C
		∞	∞	∞	2	2	1	20°C

- 6) Repack unused devices with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 8) Devices must be baked for 10~24 hours at 60 ± 5 °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge current. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leakage current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead to a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires. In order to prevent these problems, we recommend users to know the physical properties of materials used in luminaires and they must be carefully selected.
- 11) Risk of sulfurization (or tarnishing)
 The LED from Samsung uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (Cl) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as rubber, plain paper, lead solder cream, etc.

Legal and additional information.

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The company is redefining the worlds of TVs, smartphones, wearable devices, tablets, digital appliances, network systems, and memory, system LSI, foundry and LED solutions. For the latest news, please visit the Samsung Newsroom at news.samsung.com.

Samsung provides limited warranty for its LED products, the full text of which is available at <https://www.samsung.com/led/support/warranties>

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The Samsung logo, consisting of the word "SAMSUNG" in a bold, blue, sans-serif font.